F Fuji Electric **FMH28N50E**

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

Features

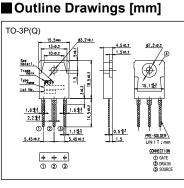
Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (3.0±0.5V) High avalanche durability

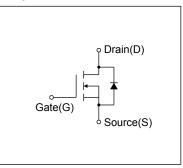
Applications

Switching regulators UPS (Uninterruptible Power Supply) **DC-DC converters**

Maximum Ratings and Characteristics

Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)





Equivalent circuit schematic

Description	Symbol	Characteristics	Unit	Remarks
Drain Source Veltere	VDS	500	V	
Drain-Source Voltage	VDSX	500	V	V _{GS} = -30V
Continuous Drain Current	lo	±28	А	
Pulsed Drain Current	IDP	±112	А	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum AvalancheCurrent	lar	28	А	Note*1
Non-Repetitive Maximum Avalanche Energy	EAS	1033.1	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	40	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	10.9	kV/µs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maulinum Danna Diagliagéigu	PD	2.50	14/	Ta=25°C
Maximum Power Dissipation		400	W	Tc=25°C
On another and Otana as Tanana and an analy	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to + 150	°C	

• Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions	Conditions		typ.	max.	Unit
Drain-Source Breakdown Voltage	BVDSS	I _D =250μA, V _{GS} =0V		500	-	-	V
Gate Threshold Voltage	Vgs (th)	ID=250µA, VDS=VGS		2.5	3.0	3.5	V
Zero Gate Voltage Drain Current		V _{DS} =500V, V _{GS} =0V	Tch=25°C	-	-	25	μΑ
	IDSS	V _{DS} =400V, V _{GS} =0V	Tch=125°C	-	-	250	
Gate-Source Leakage Current	Igss	Vgs=±30V, Vds=0V	V _{GS} =±30V, V _{DS} =0V		10	100	nA
Drain-Source On-State Resistance	RDS (ON)	I _D =14A, V _{GS} =10V		-	0.16	0.19	Ω
Forward Transconductance	g _{fs}	ID=14A, VDS=25V		16	32	-	S
Input Capacitance	Ciss	Vos=25V Vos=0V f=1MHz		-	4400	6600	pF
Output Capacitance	Coss			-	420	630	
Reverse Transfer Capacitance	Crss			-	32	48	
Turn-On Time	td(on)	V _{cc} =300V V _{GS} =10V I _D =14A R _{GS} =5.1Ω		-	26	39	ns
	tr			-	14	21	
Turn-Off Time	td(off)			-	144	216	
	tf			-	24	36	
Total Gate Charge	QG	Vcc=250V Ic=28A Vcs=10V		-	130	195	nC
Gate-Source Charge	QGS			-	30	45	
Gate-Drain Charge	QGD			-	40	60	
Avalanche Capability	lav	L=1.04mH, T _{ch} =25°C		28	-	-	А
Diode Forward On-Voltage	Vsd	IF=28A, VGS=0V, Tch=25°C		-	0.90	1.35	V
Reverse Recovery Time	trr	IF=28A, VGS=0V		-	0.72	-	μS
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	11.2	-	μC

Thermal Characteristics

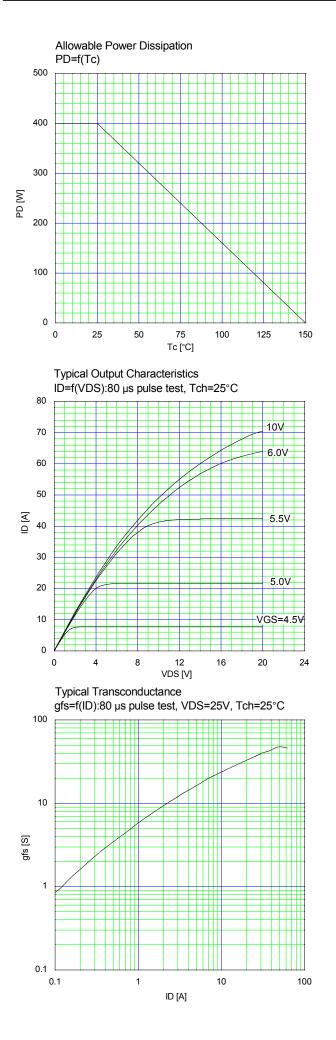
Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to Case			0.313	°C/W
	Rth (ch-a)	Channel to Ambient			50.0	°C/W

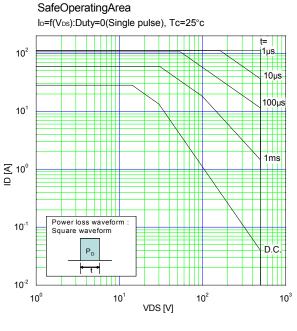
Note *1 : Tch≤150°C

Note 1 : Istaing Tch=25°C, IAs=12A, L=13.2mH, Vcc=50V, RG=50Ω EAs limited by maximum channel temperature and avalanche current. See to 'Avalanche Energy' graph.

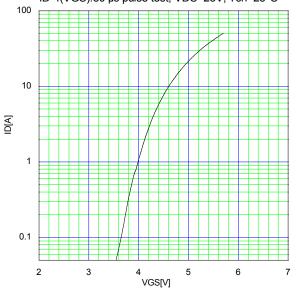
Note *3 : Repetitive rating : Pulse width limited by maximum channel temperature.

See to the 'Transient Themal impeadance' graph. Note *4 : IFS-ID, -di/dt=100A/µs, Vcc≤BVbss, Tch≤150°C. Note *5 : IFS-ID, dv/dt=10.9kV/µs, Vcc≤BVbss, Tch≤150°C.

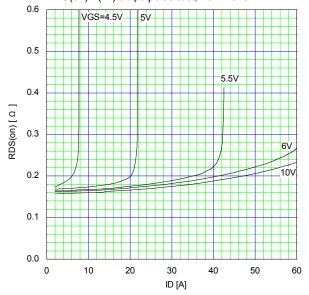


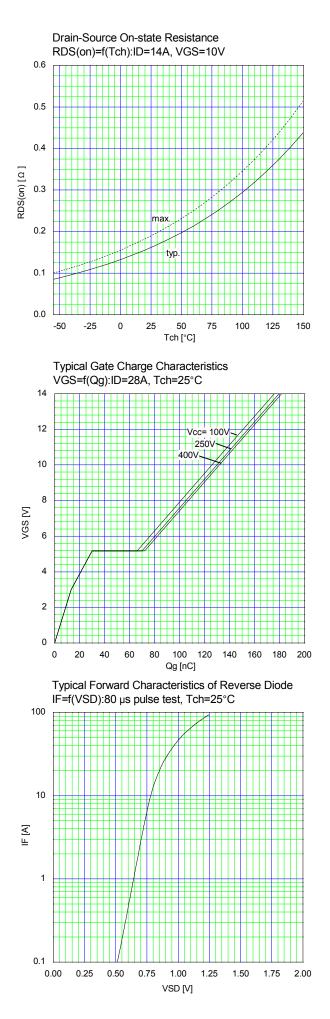


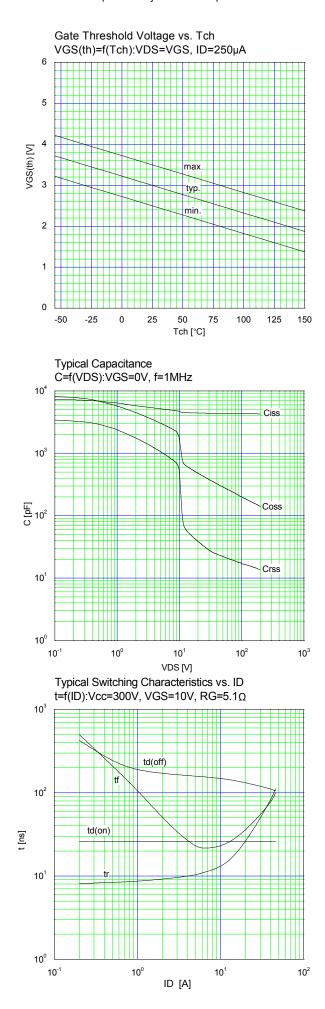
Typical Transfer Characteristic ID=f(VGS):80 μs pulse test, VDS=25V, Tch=25°C

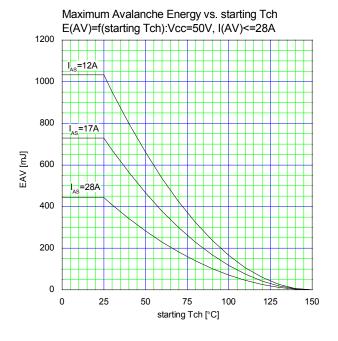


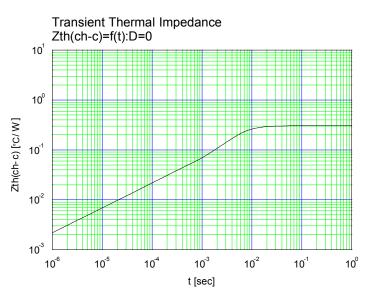
Typical Drain-Source on-state Resistance RDS(on)=f(ID):80 µs pulse test, Tch=25°C











WARNING

-

	ibject to change without not	ns, characteristics, data, materiatics, data, materiatice for specification changes or		cember 2014. g a product listed in this Catalog, b
implied, under any granted. Fuji Electi	patent, copyright, trade sec ic Co., Ltd. makes no repre		right owned by Fuji Electric express or implied, relating	
faulty. When using the equipment from	Fuji Electric semiconductor	ire, or other problem if any of the	u are requested to take ade	ductor products may become equate safety measures to prevent t is recommended to make your
4. The products intro requirements.	Juced in this Catalog are int	tended for use in the following e	lectronic and electrical equi	ipment which has normal reliability
Computers Machine tools	 OA equipment Audiovisual equipment 	Communications equipme Electrical home appliances		 Measurement equipment Industrial robots etc.
it is imperative to co	ontact Fuji Electric Co., Ltd.	equipment requiring higher reli to obtain prior approval. When the equipment from malfunctior	using these products for su	ich equipment, take adequate
	uipment (mounted on cars a	and ships)	 Trunk communication 	
 Traffic-signal cont Emergency equip Medical equipmer 	ment for responding to disa	sters and anti-burglary devices	 Gas leakage detector Safety devices 	rs with an auto-shut-off feature
6. Do not use produc (without limitation).	s in this Catalog for the equ	uipment requiring strict reliability	such as the following and e	equivalents to strategic equipment
Space equipmentSubmarine repeat		Aeronautic equipment	 Nuclear control equip 	oment
	014 by Fuji Electric Co., Ltd log may be reproduced in a	l. All rights reserved. ny form or by any means withou	t the express permission of	Fuji Electric Co., Ltd.
		this Catalog, ask Fuji Electric Co all be liable for any injury caused		efore using the product. not in accordance with instructio